

Crossover from the 2D Heisenberg to the 1D Quantum Spin Ladder Regime in Underdoped High T_c Cuprates

V.V. Moshchalkov

Laboratorium voor Vaste-Stoffysica en Magnetisme,
Celestijnenlaan 200 D, 3001 Leuven, Belgium

The enigmatic scaling behaviour of the normal state properties of the high T_c cuprates has been explained by assuming that a crossover from the two-dimensional Heisenberg (2D-H) to the one-dimensional spin ladder (1D-SL) regime takes place at temperature $T \simeq T^*$. For $T < T^*$ stripe formation results in the quantum 1D transport with the characteristic inelastic length L_ϕ being fully controlled by the magnetic correlation length ξ_m of the even-chain SL, whereas for $T > T^*$ the 2D quantum transport is realized with L_ϕ governed by the 2D-H correlations $L_\phi \simeq \xi_m \sim \exp(J/T)$. Therefore, the pseudogap found in underdoped ($p < p_{\text{opt}}$) high T_c 's is the spin-gap $\Delta(p)$ in even-chain 1D-SL.

During the last decade an impressive progress has been made in developing an adequate description of the evolution of the high T_c 's normal state properties with the hole doping p (for recent overviews see Ref. 1–5). For underdoped ($p < p_{\text{opt}}$) high T_c cuprates a convincing scaling behaviour has been demonstrated for transport [6–8], NMR [9,10] and other data. The established generalized $T - p$ phase diagram contains one (or two) characteristic scaling temperatures $T^*(p)$ decreasing with p and associated with the existence of the pseudogap at $T < T^*(p)$. While the existence of the $T^*(p)$ line on the $T - X$ diagram is by now widely accepted, the origin of $T^*(p)$ and the pseudogap has not yet been clarified.

The dependence $T^*(p)$ can be easily found from the scaling analysis of the normal state resistivity $\rho(T, p)$ by taking T^* as the temperature below which a pronounced deviation of ρ from the linear ρ vs T behaviour is seen. Therefore, the key factor in revealing the origin of T^* is the identification of the mechanisms responsible for the specific ρ vs T variation at both $T > T^*$ (linear $\rho(T)$) and $T < T^*$ (superlinear $\rho(T)$). Generalizing the ideas formulated for high T_c 's in the previous publication [11], it will be assumed here that (i) the dominant scattering mechanism in the whole temperature range is of magnetic origin; (ii) the specific temperature dependence of resistivity, $\rho(T)$, can be described by the inverse quantum conductivity σ^{-1} with the inelastic length L_ϕ being fully controlled, via a strong interaction of holes with Cu^{2+} spins, by the magnetic correlation length ξ_m , and, finally, (iii) 2D and 1D expressions should be used for calculating conductivity at $T > T^*$ and $T < T^*$, respectively:

$$\rho_{2D}^{-1}(T) = \sigma_{2D}(T)|_{L_\phi=\xi_m} = \frac{1}{b} \frac{e^2}{\hbar} \ln(\xi_{m2D}(T)/\ell) \quad (1)$$

$$\rho_{1D}^{-1}(T) = \sigma_{1D}(T)|_{L_\phi=\xi_m} = \frac{1}{b} \frac{e^2}{\hbar} \xi_{m1D}(T) \quad (2)$$

Here ℓ is the elastic length and b is the thickness of the 2D film or diameter of the 1D wire [12]. In Ref. 11 it has been shown that the high temperature ($T > T^*$) transport properties of the high T_c cuprates can be successfully explained in terms of the quantum 2D transport with L_ϕ controlled by ξ_m corresponding to the 2D Heisenberg magnetic correlation length [13,14]:

$$\xi_{m2D}(T) = \frac{e}{8} \frac{\hbar c}{2\pi F^2} \left(1 - \frac{1}{2} \frac{T}{2\pi F^2}\right) \exp\left(\frac{2\pi F^2}{T}\right) \quad (3)$$

with $2\pi F^2 \simeq J$. In this case the most remarkable transport property – linear $\rho(T)$ behaviour – is simply found by taking $\ln$ (Eq. 1) from the exponent (Eq. 3)

$$\sigma_{2D} \sim \ln \xi_m \sim \ln \left(\exp \frac{J}{T} \right) \sim \frac{J}{T}$$

which gives a linear ρ vs T dependence with the slope determined through the exchange coupling J [11]. The transition from convex (underdoped) via linear (optimally doped) to concave (overdoped) shape of the $\rho(T)$ curves, induced by doping, as well as the absolute $\rho(T)$ value, are also reproduced in this case [11].

In the present paper it will be shown that the application of the 1D scenario (Eq. 2) below T^* with ξ_m determined by the correlation length for the quantum spin ladder (SL) with an even number of legs n_c [15]

$$(\Delta \xi_{m1D})^{-1} = 2/\pi + A(T/\Delta) \exp(-\Delta/T) \quad (4)$$

in combination with the 2D scenario at $T > T^*$ (Eq. 1 and Eq. 3) gives a convincing and consistent explanation of the whole scaled dependence $\rho/\rho_0(T_0) = f(T/T_0)$ with $T^* \simeq 0.8T_0$. This proves that $T^*(p)$ corresponds to the crossover temperature between the high temperature 2D Heisenberg and the low temperature 1D SL regime existing, most probably, at $T_c(p) < T < T^*(p)$. This implies also the formation of the 1D stripes in the CuO_2 planes. The validity of the $\sigma_{1D} \sim \xi_{m1D}$ approach has been checked directly by applying it first to the SL cuprate $\text{Sr}_{2.5}\text{Ca}_{11.5}\text{Cu}_{24}\text{O}_{41}$ where 1D stripes are just imposed by the available crystal structure. This approach has resulted in the fit of a remarkable quality. Finally, the scaling behaviour of the Knight shift in $\text{YBa}_2\text{Cu}_3\text{O}_x$ has also been interpreted in the framework of the 1D stripes scenario.

A rapidly growing experimental evidence, indicating the possibility of the stripes formation [1,3,16,17], stimulates the interest to the 1D mechanism of conductivity via charge stripes forming the lowest resistance path. Therefore it seems to be very important to calculate conductivity in the 1D regime, keeping in mind an emerging reality of the stripes formation in the 2D CuO_2 planes of the high T_c cuprates [3,16,17]. However, at least at this stage, it is still a bit uncomfortable to apply a pure 1D model to materials where Cu and O orbitals form a well defined 2D system.

To overcome this psychological barrier and to verify the validity of the proposed 1D SL model $\sigma_{1\alpha} \sim \xi_{m1D}$, we will use it first for the description of the resistivity data obtained on the novel even-chain spin ladder compound $\text{Sr}_{2.5}\text{Ca}_{11.5}\text{Cu}_{24}\text{O}_{41}$ [18]. This compound definitely contains two-leg ($n_c = 2$) Cu_2O_3 ladder and therefore its resistivity along the ladder direction should indeed obey Eq. 2 with ξ_{m1D} given by the recent Monte Carlo calculations [15], through the admixture of the linear temperature dependence of ξ_{m1D}^{-1} with the exponential term containing the spin gap Δ and constant $A \simeq 1.7$ (see Eq. 4). The results of the fit are shown in Fig. 1. This fit demonstrates a remarkable quality over the whole temperature range $T \simeq 25\text{--}300$ K, except for the lowest temperatures where the onset of the localization effects, not considered here, is clearly visible in experiment [18]. Moreover, the used fitting parameters ρ_0 , C and Δ in

$$\rho(T) = \rho_0 + CT \exp\left(-\frac{\Delta}{T}\right) = \frac{\hbar b^2}{e^2 a} \left\{ \frac{2\Delta}{\pi J_{\parallel}} + A \frac{T}{J_{\parallel}} \exp\left(-\frac{\Delta}{T}\right) \right\} \quad (5)$$

all show very reasonable values. The expected residual resistance $\rho_0 = \frac{\hbar b^2}{e^2 a} \frac{2\Delta}{\pi J_{\parallel}}$ for $b \sim 2a \sim 7.6 \text{ \AA}$, $\Delta \sim 200$ K (Fig. 1) and $J_{\parallel} \simeq 1400$ K (the normal value for the CuO_2 planes) is $\rho_0 \simeq 0.5 \cdot 10^{-4} \Omega\text{cm}$ which is in a good agreement with $\rho_0 = 0.824 \times 10^{-4} \Omega\text{cm}$ found from the fit. The fitted gap $\Delta \simeq 213$ K (Fig. 1) is close to $\Delta = 320$ K determined for the undoped SL SrCu_2O_3 from the inelastic neutron scattering experiments [19]. In doped systems it is natural to expect the reduction of the spin gap. Therefore the difference between the fitted value (213 K) and the measured one in an undoped system (320 K) seems to be quite fair. Finally the calculated fitting parameter C is $C = \frac{\rho_0 A \pi}{2\Delta} = 0.0103$ (in units of $10^{-4} \Omega\text{cm/K}$) to be compared with $C = 0.0182$ (see Fig. 1). Fixing the C value via known ρ_0 and Δ produces the fit of a comparable quality, but this time only with the two fitting parameters ρ_0 and Δ .

Having the validity of Eq. 5 checked on the real 1D even-chain SL compounds, it is worth to try to use it at temperatures $T < T^*$ in 2D high T_c 's where 1D stripes might be formed. Now it is not evident at all that the scaled $\rho/\rho(T_0) = f(T/T_0)$ (Fig. 2a) could be also fitted with the 1D Eq. 5. From the master $\rho/\rho(T_0)$ vs T/T_0 curve [7] (Fig. 2a) the averaged data points (see open circles in Fig. 2b) were used to be fitted by Eq. 5. The results of the fit are given in Fig. 2b by solid lines. First of all, at high temperatures $T > T^* \simeq 0.8T_0$ we clearly see the anticipated linear 2D behaviour [11] $\rho \sim T/J$ with $J \sim T_0$. Secondly, at $T < T^*$ the fit with Eq. 5 with the argument $t = T/T_0$ again gives an excellent result. It is also clearly seen, by comparing $\rho(T)$ curves at $T < T^*$ with $\rho(T)$ curves measured for 1D SL compounds (Fig. 1), that the concave segment of the high T_c $\rho(T)$ curve at $T < T^*$ looks very much like the $\rho(T)$ curve for the 1D even-chain SL systems. The fitting parameter Δ , in units of T_0 , is now $0.49 T_0$, in agreement with the spin-gap $\Delta \simeq 0.41 J_{\perp}$ calculated for the weak-coupling regime of the $n_c = 2$ SL [15].

Therefore, the scaling behaviour of resistivity below T^* ($\rho \sim \xi_{m1D}$) simply reflects the scaling curve anticipated for the magnetic coherence length ξ_{m1D} in the $n_c = 2$ SL (see Fig. 5 in Ref. 15). Then the observed decrease of $T^*(p)$ (or $T_0(p)$) [1,4,6–10] should be related to the reduction of $J_{\perp}$ and the spin gap Δ in SL with doping. Since the holes are concentrated in stripes corresponding to SLs, then the doping level, affecting $J_{\perp}$ and $J_{\parallel}$ in SL, could differ substantially and therefore one should expect smaller $J_{\perp}$ and $J_{\parallel}$ than the exchange constant J in the surrounding Mott insulator phase from where the charges are expelled into the stripes.

The formation of stripes brings into the system an intrinsic doping inhomogeneity resulting in the reduction of dimensionality from 2D to 1D. In resistivity measurements the most conducting paths (stripes) are selected automatically and this makes the $\rho(T)$ data so sensitive to the formation of stripes. However, it is not clear to what extent stripes dominate other properties which may integrate the response from both stripes and the surrounding Mott insulator phase. In this respect it is important to apply the same approach in analyzing other scaled physical properties. Since in $\text{YBa}_2\text{Cu}_3\text{O}_x$ the same scaling temperature $T_0(p)$ works equally well for resistivity and the Knight shift data [7], the latter can also be used for fitting with the 1D SL model.

As a result, the susceptibility $\chi(T)$ (and $K(T)$) should obey the following dependence [15,19]:

$$\chi(n_c, J_\perp; T) \sim T^{-1/2} \exp(-\Delta/T). \quad (6)$$

Fitting of the scaled $K(T)$ data with this expression (Fig. 3) gives a good result, though requires the second fitting parameter K_0 – the Knight shift at $T \rightarrow 0$. In this case the obtained gap $\Delta(p) = 1.24 T_0(p)$ (Fig. 3) is higher than $\Delta(p) = 0.49 T_0$ found from the analysis of the scaled resistivity at $T < T^*$ (Fig. 2b). This difference could be caused by a contribution into $K(T)$ from atoms inside the Mott insulator domains close to the stripes. At the same time such a contribution should be irrelevant for the dc transport which is normally provided by the most conducting domains, i.e. stripes themselves.

In summary, the novel approach to the description of the scaling behaviour of the high T_c 's normal state properties and the existence of the pseudogap has been developed. It is based on the assumption that dc transport in high T_c 's is caused by the quantum conductivity with the inelastic length $L\phi$ fully governed by the magnetic correlation length ξ_m . Depending upon the effective dimensionality – 2D ($T > T^*$) or 1D (stripes at $T < T^*$) (Fig. 4) – conductivity is found from $\sigma_{2D} \sim \ln \xi_{m2D}$ (Eq. 1) and $\sigma_{1D} \sim \xi_{m1D}$ (Eq. 2), respectively. The validity of the $\sigma_{1D} \sim \xi_{m1D}$ approach has been checked directly using resistivity data for real SL systems. Then it was successfully applied also for the description of the low temperature ($T < T^*$) behaviour of the scaled resistivity. In the framework of the proposed approach the pseudogap temperature $T^*(p)$ is the crossover between the high temperature 2D Heisenberg and the 1D quantum even-chain SL regime. The latter is established as temperature decreases and charge expulsion from the Mott insulator phases [20] gets stronger and finally leads to the formation of well defined stripes which can be modelled by the SL with an even n_c . The effective 1D case at $T < T^*$ makes all considerations of the non-Fermi liquid behaviour [3,5,21] and possible charge/spin separation [22,23] important for the physics of underdoped high T_c 's. The weakly doped even-chain SLs have the spin-gap, show hole-hole pairing (though rather short-range along the chain) with an "approximate" $d_{x^2-y^2}$ symmetry [24]. These materials, being lightly doped insulators, show also features of a large metal-like Fermi surface. Since the 1D SL phase precedes the superconducting transition, then it is quite reasonable to consider similar mechanisms being responsible for superconductivity in both underdoped cuprates and in SL with even n_c [24]. The short-range correlation for the pairs along the chains in even-leg SLs [25] contradicts ARPES and corner-junction SQUID measurements carried out at $T < T_c(p)$. This can be explained by a substantial modification of these correlations due to the onset at $T \approx T_c(p)$ of the Josephson-like coupling between the stripes [3], resulting eventually in an effective recovery of the 2D-character of the Cu-O system at $T < T_c(p)$. The Josephson-like coupling between the 1D SL results in the onset of superconductivity at $T_c(p)$ with the $T_c(p)$ value increasing with the hole doping. Isolated 1D even-chain SLs, most probably, have no chance to develop along the chain a real macroscopic superconducting coherence of bosons, formed along rungs in the SL. From this point of view, recent pulsed field data [26] can be interpreted as an experimental evidence of the insulating ground state of field-decoupled SLs in underdoped cuprates.

The 1D SL phase becomes unstable at high temperatures, when entropy effects cause stripe meandering and eventually destroy the 1D stripes [16], and at high doping levels, when the distance between the stripes becomes so small that the Mott insulator phase between stripes collapses, thus leading to a recovery of the 2D regime. As a result, in optimally doped and overdoped regime the superconducting transition takes place when the CuO₂ layer is in the regime of the 2D doped Heisenberg system. Therefore, the 1D SL phase seems to exist only in underdoped cuprates in the temperature window between $T^*(p)$ and $T_c(p)$.

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FIGURE CAPTIONS

- Fig. 1 Temperature dependence of resistivity for the even-chain spin-ladder single crystal $\text{Sr}_{2.5}\text{Ca}_{11.5}\text{Cu}_{24}\text{O}_{41}$: circles – experimental data of Nagata et al. [18], solid line – fit using Eq. 5 describing resistivity of the 1D even-chain spin-ladders.
- Fig. 2 (a) Scaled in-plane resistivity for the $\text{YBa}_2\text{Cu}_3\text{O}_x$ system (after Ref. 7).
 (b) Circles – the averaged data points of the scaled in-plane resistivity, solid lines – the fit using Eq. 5 at $T \lesssim T^*$ (resistivity of the 1D even-chain spin-ladder at $T \lesssim T^*$) and Eq. 1 and Eq. 3 at $T \gtrsim T^*$ (resistivity of the 2D Heisenberg systems).
- Fig. 3 Scaled Knight shift data (open circles) of Alloul (Phys. Rev. Lett. **63**, 689 (1989)), after Ref. 7. The scaling parameter T_0 is the same as the one used for scaling of in-plane resistivity of $\text{YBa}_2\text{Cu}_3\text{O}_x$ samples (Fig. 2a). The solid line is the fit with Eq. 6.
- Fig. 4 Schematic phase diagram of layered high T_c cuprates.









